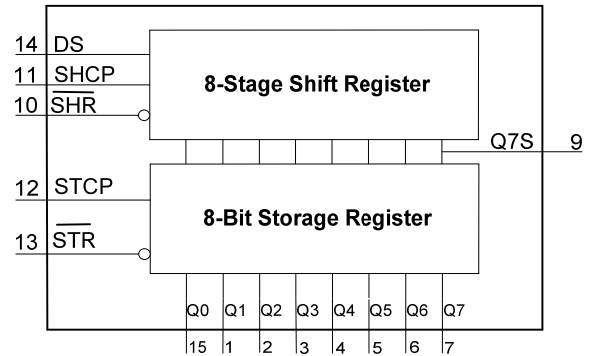


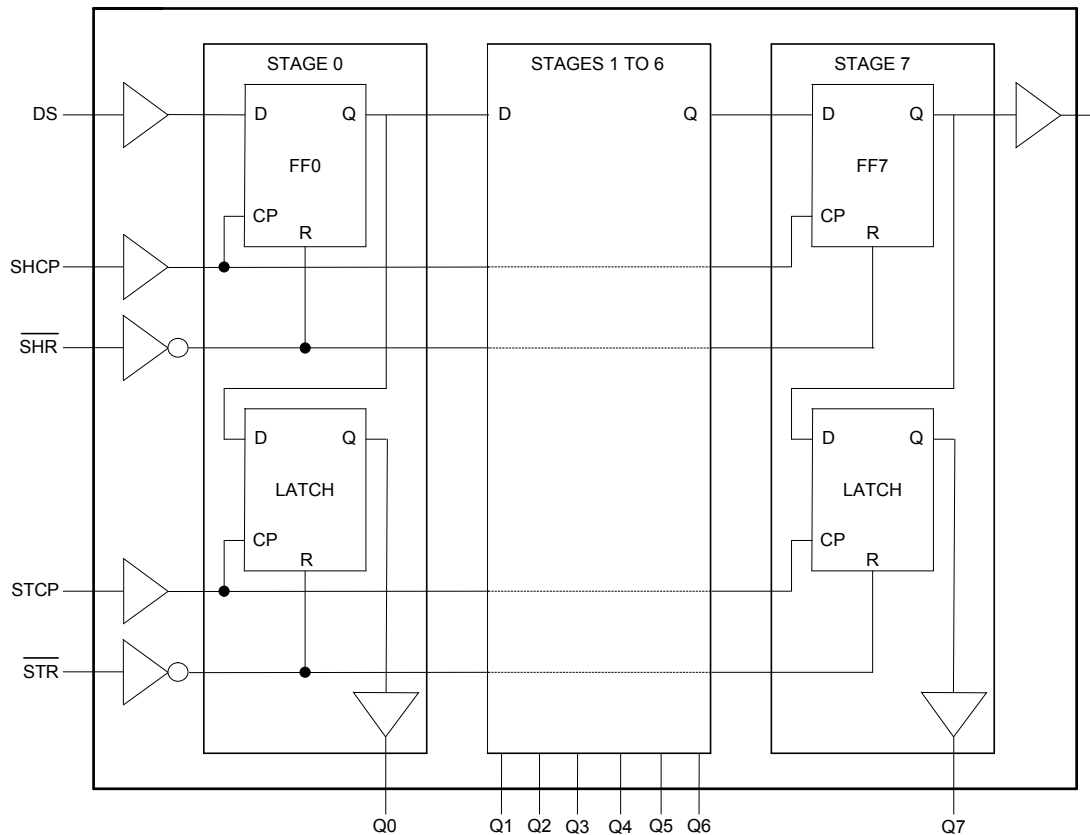
## Pin Descriptions

Pin Number	Pin Name	Functions
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	$\overline{\text{SHR}}$	Shift Register Reset active low
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	$\overline{\text{STR}}$	Storage Register Reset active low
14	DS	Serial Data input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

## Functional Diagram



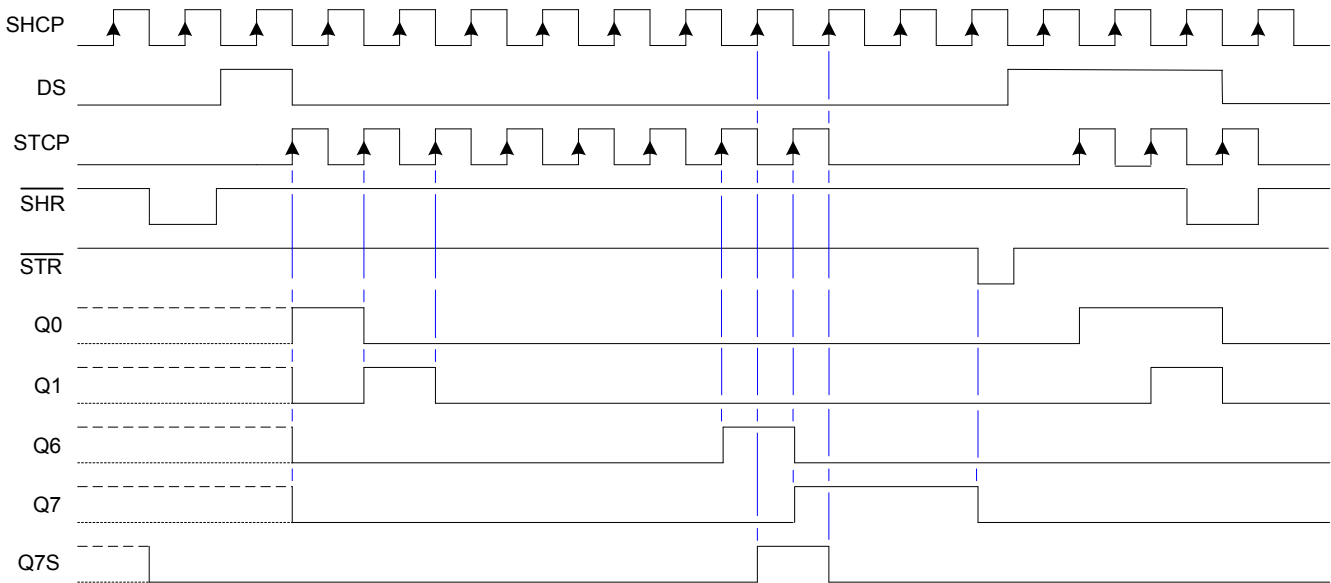
## Logic Diagram



## Functional Description and Timing Diagram

Control				Input	Output		Function
SHR	STR	SHCP	STCP	DS	Q7S	Qn	
L	X	X	X	X	L	NC	Clear Shift Register
X	L	X	X	X	NC	L	Clear Storage Register
H	X	↑	L	H or L	Q6S	NC	Loads DS into shift register stage 0. All Q <sub>S</sub> shifted
H	H	X	↑	X	NC	Qs	Contents of shift register moved to storage register all Q <sub>S</sub> → Q <sub>N</sub>
H	H	↑	↑	H or L	Q6S	QnS	Shift Register one pulse count ahead of storage register.

H=HIGH voltage state  
 L=LOW voltage state  
 ↑=LOW to HIGH transition  
 X= don't care – high or low (not floating)  
 NC= No change



## Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
V <sub>I</sub>	Input Voltage Range	-0.5 to +7.0	V
V <sub>O</sub>	Voltage applied to output in high or low state	-0.3 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> < -0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> > V <sub>CC</sub> +0.5V	20	mA
I <sub>O</sub>	Continuous output current	±25	mA
I <sub>CC</sub>	Continuous current through V <sub>CC</sub>	75	mA
I <sub>GND</sub>	Continuous current through GND	-75	mA
T <sub>J</sub>	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

**Recommended Operating Conditions** (Note 5) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	–	2.0	5.5	V
V <sub>I</sub>	Input Voltage	–	0	5.5	V
V <sub>O</sub>	Output Voltage	–	0	V <sub>CC</sub>	V
Δt/ΔV	Input transition Rise or Fall Rate	V <sub>CC</sub> = 3.0V to 3.6V	–	100	ns/V
		V <sub>CC</sub> = 4.5V to 5.5V	–	20	
T <sub>A</sub>	Operating Free-Air Temperature	–	–40	+125	°C

Note: 5. Unused inputs should be held at V<sub>CC</sub> or Ground.

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = +25°C			T <sub>A</sub> = –40°C to +85°C		T <sub>A</sub> = –40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage	–	2.0V	1.5	–	–	1.5	–	1.5	–	V
		–	3.0V	2.1	–	–	2.1	–	2.1	–	
		–	5.5V	3.85	–	–	3.85	–	3.85	–	
V <sub>IL</sub>	Low-Level Input Voltage	–	2.0V	–	–	0.5	–	0.5	–	0.5	V
		–	3.0V	–	–	0.9	–	0.9	–	0.9	
		–	5.5V	–	–	1.65	–	1.65	–	1.65	
V <sub>OH</sub>	High-Level Output Voltage	I <sub>OH</sub> = –50μA	2.0V	1.9	2.0	–	1.9	–	1.9	–	V
		I <sub>OH</sub> = –50μA	3.0V	2.9	3.0	–	2.9	–	2.9	–	
		I <sub>OH</sub> = –50μA	4.5V	4.4	4.5	–	4.4	–	4.4	–	
		I <sub>OH</sub> = –4mA	3.0V	2.58	–	–	2.48	–	2.40	–	
		I <sub>OH</sub> = –8mA	4.5V	3.94	–	–	3.80	–	3.70	–	
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OL</sub> = 50μA	2.0V	–	0	0.1	–	0.1	–	0.1	V
		I <sub>OL</sub> = 50μA	3.0V	–	0	0.1	–	0.1	–	0.1	
		I <sub>OL</sub> = 50μA	4.5V	–	0	0.1	–	0.1	–	0.1	
		I <sub>OL</sub> = 4mA	3.0V	–	–	0.36	–	0.44	–	0.55	
		I <sub>OL</sub> = 8mA	4.5V	–	–	0.36	–	0.44	–	0.55	
I <sub>I</sub>	Input Current	V <sub>I</sub> = GND or 5.5V	5.5V	–	0.01	± 0.1	–	± 1	–	± 2	μA
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = GND or V <sub>CC</sub> I <sub>O</sub> = 0	5.5V	–	–	4	–	40	–	80	μA
C <sub>i</sub>	Input Capacitance	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5V	–	3.5	10	–	10	–	10	pF

## Switching Characteristics

Symbol / Parameter	Pins	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
f <sub>MAX</sub> Maximum Frequency	SHCP or STCP	Figure1	3.0V to 3.6V	80	125	—	70	—	65	—	MHz
			4.5V to 5.5V	90	70	—	80	—	70	—	
t <sub>w</sub> Pulse Width	SHCP and STCP HIGH or LOW	Figure1	3.0V to 3.6V	6.0	—	—	6.5	—	7.0	—	ns
			4.5V to 5.5V	5.5	—	—	6.0	—	6.5	—	
	SHR and STR HIGH or LOW	Figure1	3.0V to 3.6V	5.0	—	—	5.0	—	5.5	—	
			4.5V to 5.5V	5.0	—	—	5.2	—	5.7	—	
t <sub>su</sub> Set-up Time	DS to SHCP	Figure1	3.0V to 3.6V	3.5	—	—	3.5	—	3.5	—	ns
			4.5V to 5.5V	3.0	—	—	3.0	—	3.0	—	
	SHR to STCP	Figure1	3.0V to 3.6V	8.0	—	—	9.0	—	9.5	—	
			4.5V to 5.5V	5.0	—	—	5.0	—	5.5	—	
	SHCP tp STCP	Figure1	3.0V to 3.6V	8.0	—	—	8.5	—	9.0	—	ns
			4.5V to 5.5V	5.0	—	—	5.0	—	5.5	—	
t <sub>h</sub> Hold Time	DS to SHCP	Figure1	3.0V to 3.6V	1.5	—	—	1.5	—	1.5	—	ns
			4.5V to 5.5V	2.0	—	—	2.0	—	2.0	—	
t <sub>REC</sub> Recovery Time	SHR to SHCP	Figure1	3.0V to 3.6V	4.2	—	—	4.8	—	5.3	—	ns
			4.5V to 5.5V	2.9	—	—	3.3	—	3.8	—	
	SHR to STCP	Figure1	3.0V to 3.6V	4.6	—	—	5.3	—	5.8	—	ns
			4.5V to 5.5V	3.2	—	—	3.7	—	4.3	—	
t <sub>PLH</sub> LOW to HIGH Propagation Delay	SHCP to Q7S	Figure1 C <sub>L</sub> = 15pF	3.0V to 3.6V	—	5.2	8.5	2.2	9.7	2.2	10.6	ns
			4.5V to 5.5V	—	3.8	6.3	1.7	7.2	1.7	7.8	
		Figure1 C <sub>L</sub> = 50pF	3.0V to 3.6V	—	7.4	11.5	3.0	13.2	3.0	14.3	
			4.5V to 5.5V	—	4.8	8.0	2.4	9.1	2.4	10.0	
	STCP to Qn	Figure1 C <sub>L</sub> = 15pF	3.0V to 3.6V	—	5.1	8.3	2.3	9.5	2.3	10.6	ns
			4.5V to 5.5V	—	3.5	5.7	1.8	6.5	1.8	7.1	
		Figure1 C <sub>L</sub> = 50pF	3.0V to 3.6V	—	7.3	11.9	3.3	13.6	3.3	14.7	
			4.5V to 5.5V	—	4.8	7.8	2.6	9.0	2.6	9.8	

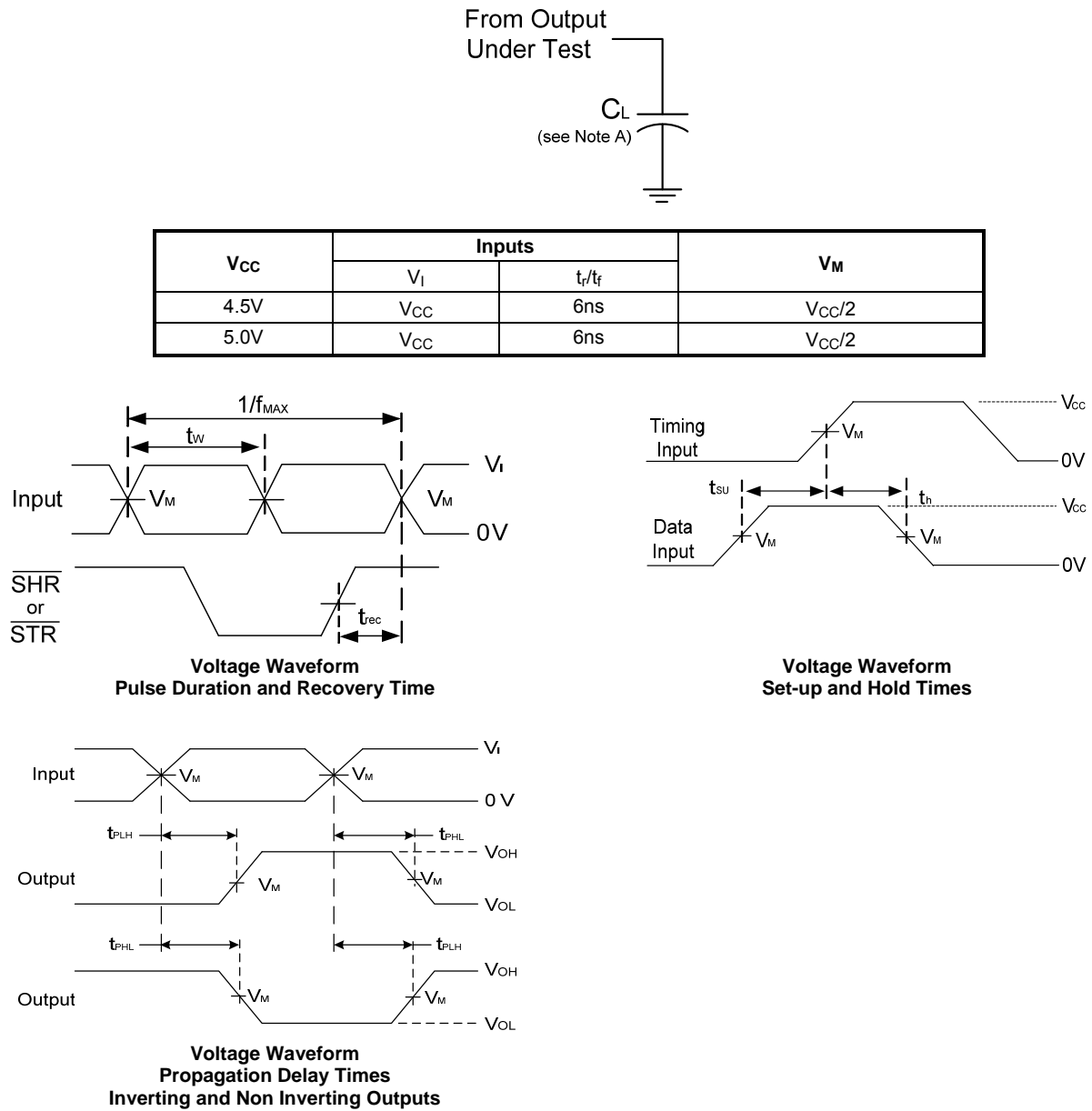
**Switching Characteristics (cont.)**

Symbol / Parameter	Pins	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t <sub>PHLH</sub> HIGH to LOW Propagation Delay	SHCP to Q7S	Figure 1 C <sub>L</sub> = 15pF	3.0V to 3.6V	–	5.5	8.9	2.3	10.2	2.3	11.0	ns
			4.5V to 5.5V	–	4.1	6.7	1.9	7.6	1.9	8.2	
		Figure 1 C <sub>L</sub> = 50pF	3.0V to 3.6V	–	7.4	12.1	3.0	13.9	3.0	15.1	
			4.5V to 5.5V	–	5.4	8.8	2.5	10.1	2.5	11.0	
	STCP to Qn	Figure 1 C <sub>L</sub> = 15pF	3.0V to 3.6V	–	5.5	9.1	2.4	10.4	2.4	11.3	ns
			4.5V to 5.5V	–	3.7	6.0	1.9	6.9	1.9	7.5	
		Figure 1 C <sub>L</sub> = 50pF	3.0V to 3.6V	–	7.3	12.0	3.2	13.8	3.2	15.0	
			4.5V to 5.5V	–	5.2	8.5	2.6	9.7	2.6	10.5	
	$\overline{\text{SHR}}$ to Q7S	Figure 1 C <sub>L</sub> = 15pF	3.0V to 3.6V	–	5.7	9.5	2.3	10.8	2.3	11.7	ns
			4.5V to 5.5V	–	4.1	6.7	2.0	7.6	2.0	8.2	
		Figure 1 C <sub>L</sub> = 50pF	3.0V to 3.6V	–	7.5	12.2	3.6	14.0	3.6	15.2	
			4.5V to 5.5V	–	5.4	8.8	2.8	10.1	2.8	11.0	
	$\overline{\text{STR}}$ to Qn	Figure 1 C <sub>L</sub> = 15pF	3.0V to 3.6V	–	4.1	7.2	2.2	8.2	2.2	8.9	ns
			4.5V to 5.5V	–	4.1	7.2	2.2	8.2	2.2	8.9	
		Figure 1 C <sub>L</sub> = 50pF	3.0V to 3.6V	–	5.4	9.4	3.0	10.7	3.0	11.6	
			4.5V to 5.5V	–	5.4	9.4	3.0	10.7	3.0	11.6	
t <sub>PHL</sub> Propagation Delay	$\overline{\text{SHR}}$ to Q7S	Figure 1	2.0V	–	39	150	–	185	–	225	ns
			4.5V	–	14	30	–	37	–	45	
			5.0V	–	11	–	–	–	–	–	
			6.0V	–	12	26	–	31	–	38	
	$\overline{\text{STR}}$ to Qn	Figure 1	2.0V	–	39	125	–	155	–	185	ns
			4.5V	–	14	25	–	31	–	37	
			5.0V	–	11	–	–	–	–	–	
			6.0V	–	12	21	–	26	–	31	
t <sub>THL</sub> Transition Time	Serial data output Q7S	Figure 1	2.0V	–	19	75	–	95	–	110	ns
			4.5V	–	7	15	–	19	–	22	
			6.0V	–	6	13	–	16	–	19	
	Parallel Data Outputs Q <sub>N</sub>	Figure 1	2.0V	–	14	60	–	75	–	90	ns
			4.5V	–	5	12	–	15	–	18	
			6.0V	–	4	10	–	13	–	15	

**Operating Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)**

Parameter		Test Conditions	V <sub>CC</sub> = 5V	Unit
			Typ	
C <sub>pd</sub>	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	51	pF

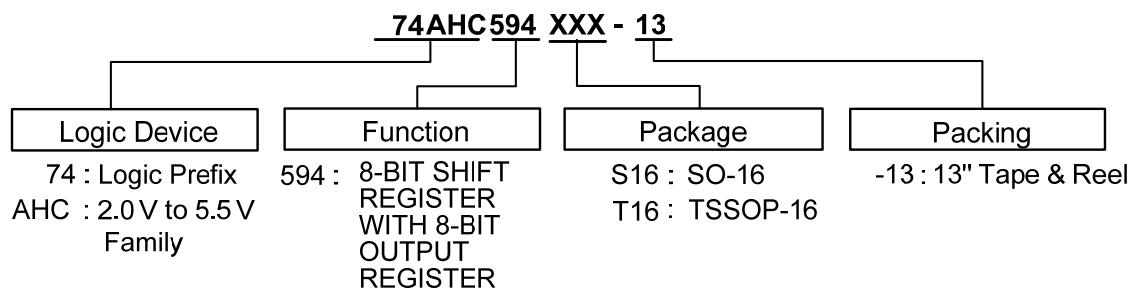
## Parameter Measurement Information



- Notes:
- A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate  $\leq 10\text{MHz}$ .
  - C. Inputs are measured separately one transition per measurement.
  - D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .

**Figure 1 Load Circuit and Voltage Waveforms**

## Ordering Information

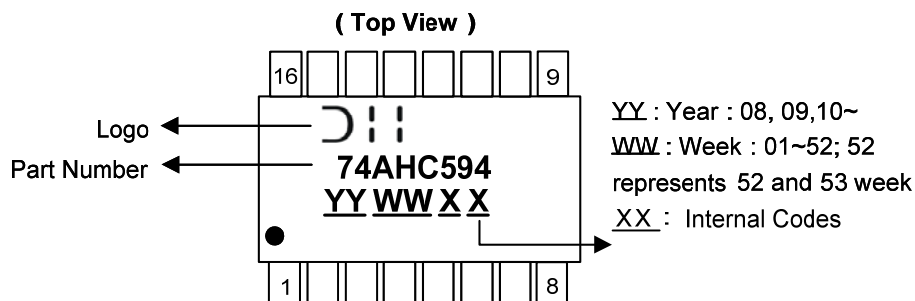


Part Number	Package Code	Packaging	7" Tape and Reel (Note 6)	
			Quantity	Part Number Suffix
74AHC594S16-13	S16	SO-16	2500/Tape & Reel	-13
74AHC594T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Note: 6. The taping orientation is located on our website at <http://www.diodes.com/datasheets/ap02007.pdf>

## Marking Information

(1) SO-16, TSSOP16

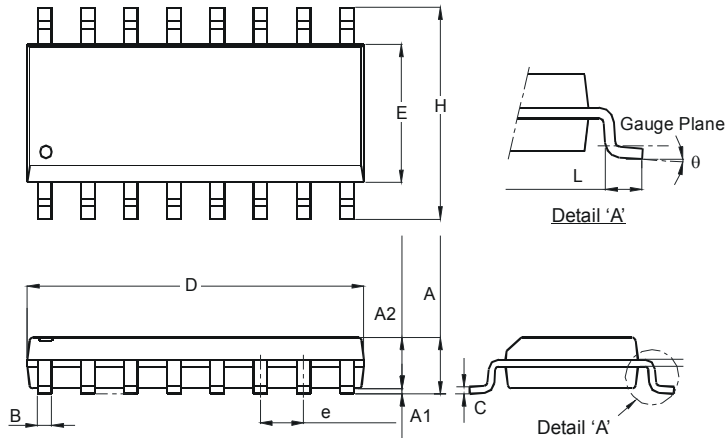


Part Number	Package
74AHC594S16	SO-16
74AHC594T16	TSSOP-16

## Package Outline Dimensions (All dimensions in mm.)

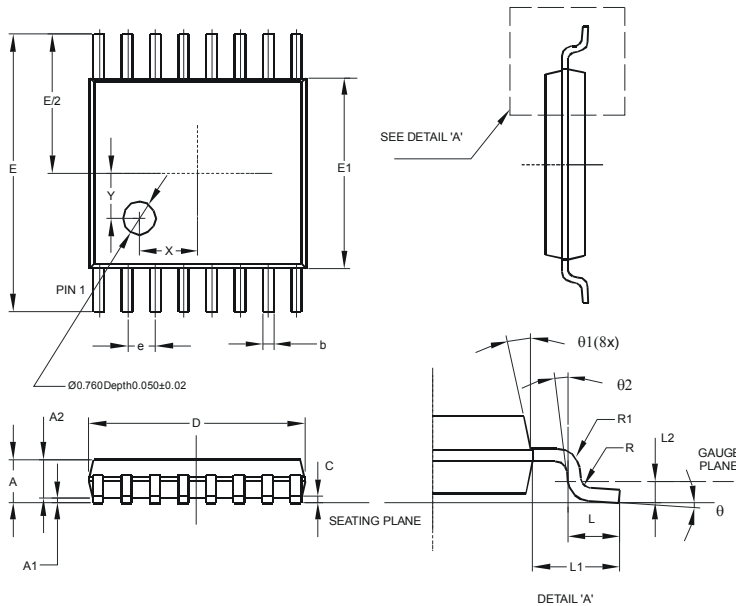
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

### Package Type: SO-16



SO-16		
Dim	Min	Max
A	1.40	1.75
A1	0.10	0.25
A2	1.30	1.50
B	0.33	0.51
C	0.19	0.25
D	9.80	10.00
E	3.80	4.00
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

### Package Type: TSSOP-16



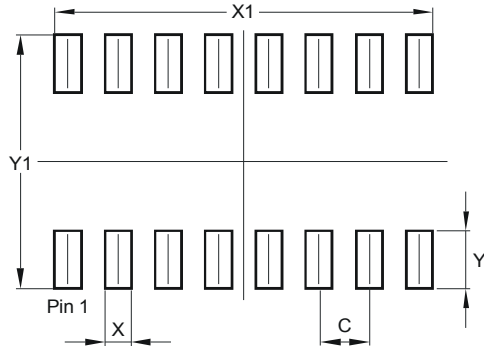
TSSOP-16			
Dim	Min	Max	Typ
A	-	1.08	-
A1	0.05	0.15	-
A2	0.80	0.93	-
b	0.19	0.30	-
c	0.09	0.20	-
D	4.90	5.10	-
E	6.40 BSC		
E1	4.30	4.50	-
e	0.65 BSC		
L	0.45	0.75	-
L1	1.00 REF		
L2	0.25 BSC		
R	0.09	-	-
R1	0.09	-	-
X	-	-	1.350
Y	-	-	1.050
θ	0°	8°	-
θ1	5°	15°	-
θ2	0°	-	-
All Dimensions in mm			



## Suggested Pad Layout

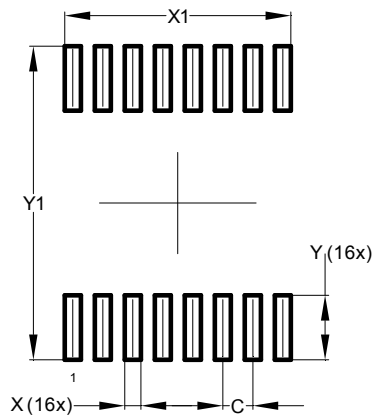
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

### Package Type: SO-16



Dimensions	Value (in mm)
C	1.270
X	0.670
X1	9.560
Y	1.450
Y1	6.400

### Package Type: TSSOP-16



Dimensions	Value (in mm)
C	0.650
X	0.350
X1	4.900
Y	1.400
Y1	6.800

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